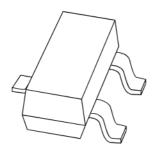
DISCRETE SEMICONDUCTORS

DATA SHEET



BC846; BC847; BC848 NPN general purpose transistors

Product specification Supersedes data of 2002 Feb 04





NPN general purpose transistors

BC846; BC847; BC848

FEATURES

- · Low current (max. 100 mA)
- · Low voltage (max. 65 V).

APPLICATIONS

· General purpose switching and amplification.

DESCRIPTION

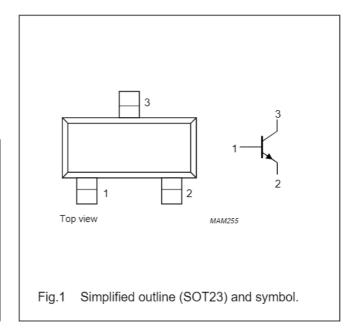
NPN transistor in a SOT23 plastic package. PNP complements: BC856, BC857 and BC858.

MARKING

TYPE NUMBER	MARKING CODE(1)
BC846	1D*
BC846A	1A*
BC846B	1B*
BC847	1H*
BC847A	1E*
BC847B	1F*
BC847C	1G*
BC848B	1K*

PINNING

PIN	DESCRIPTION	
1	base	
2	emitter	
3	collector	



Note

- 1. * = p: made in Hong Kong.
 - * = t: made in Malaysia.
 - * = W: made in China.

ORDERING INFORMATION

TYPE NUMBER	PACKAGE				
TYPE NUMBER	NAME	DESCRIPTION	VERSION		
BC846	-	plastic surface mounted package; 3 leads	SOT23		
BC846A					
BC846B					
BC847					
BC847A					
BC847B					
BC847C					
BC848B					

NPN general purpose transistors

BC846; BC847; BC848

LIMITING VALUES

In accordance with the Absolute Maximum System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS		MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter			
	BC846		-	80	V
	BC847		-	50	V
	BC848		-	30	V
V _{CEO}	collector-emitter voltage	open base			
	BC846		-	65	V
	BC847		-	45	V
	BC848		-	30	V
V _{EBO}	emitter-base voltage	open collector			
	BC846; BC847		-	6	V
	BC848		-	5	V
I _C	collector current (DC)		-	100	mA
I _{CM}	peak collector current		-	200	mA
I _{BM}	peak base current		-	200	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C; note 1	-	250	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T _{amb}	operating ambient temperature		-65	+150	°C

Note

1. Transistor mounted on an FR4 printed-circuit board, standard footprint.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT	
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air; note 1	500	K/W	

Note

1. Transistor mounted on an FR4 printed-circuit board, standard footprint.

NPN general purpose transistors

BC846; BC847; BC848

CHARACTERISTICS

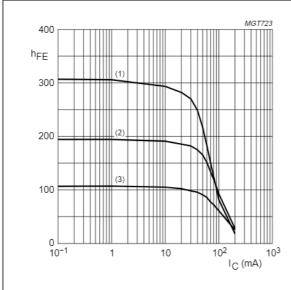
 T_{amb} = 25 °C; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CBO}	collector-base cut-off current	V _{CB} = 30 V; I _E = 0	-	-	15	nA
		$V_{CB} = 30 \text{ V; } I_{E} = 0;$ $T_{j} = 150 \text{ °C}$	-	-	5	αA
I _{EBO}	emitter-base cut-off current	V _{EB} = 5 V; I _C = 0	-	-	100	nA
h _{FE}	DC current gain	I _C = 10 ∞A; V _{CE} = 5 V				
	BC846A; BC847A		-	90	-	
	BC846B; BC847B; BC848B		-	150	-	
	BC847C		-	270	-	
	DC current gain	I _C = 2 mA; V _{CE} = 5 V				
	BC846		110	-	450	
	BC847		110	-	800	
	BC846A; BC847A		110	180	220	
	BC846B; BC847B; BC848B		200	290	450	
	BC847C		420	520	800	
V _{CEsat}	collector-emitter saturation voltage	I _C = 10 mA; I _B = 0.5 mA	T-	90	250	mV
		I_C = 100 mA; I_B = 5 mA; note 1	-	200	600	mV
V _{BEsat}	base-emitter saturation voltage	I _C = 10 mA; I _B = 0.5 mA	-	700	-	mV
		I_C = 100 mA; I_B = 5 mA; note 1	-	900	-	mV
V _{BE}	base-emitter voltage	I _C = 2 mA; V _{CE} = 5 V	580	660	700	mV
		I _C = 10 mA; V _{CE} = 5 V	-	-	770	mV
C _c	collector capacitance	V _{CB} = 10 V; I _E = I _e = 0; f = 1 MHz	-	2.5	-	pF
f _T	transition frequency	V _{CE} = 5 V; I _C = 10 mA; f = 100 MHz	100	-	-	MHz
F	noise figure	$I_C = 200 $	-	2	10	dB

Note

NPN general purpose transistors

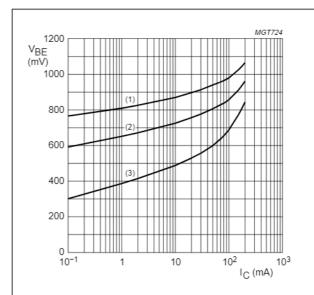
BC846; BC847; BC848



BC846A; V_{CE} = 5 V.

- (1) T_{amb} = 150 °C
- (2) T_{amb} = 25 °C.
- (3) T_{amb} = −55 °C

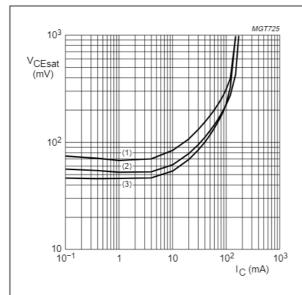
Fig.2 DC current gain as a function of collector current; typical values.



BC846A; V_{CE} = 5 V.

- (1) T_{amb} = -55 °C.
- (2) T_{amb} = 25 °C.
- (3) T_{amb} = 150 °C.

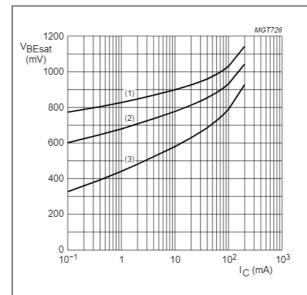
Fig.3 Base-emitter voltage as a function of collector current; typical values.



BC846A; I_C/I_B = 20

- (1) T_{amb} = 150 °C
- (2) T_{amb} = 25 °C.
- (3) T_{amb} = -55 °C.

Fig.4 Collector-emitter saturation voltage as a function of collector current; typical values.



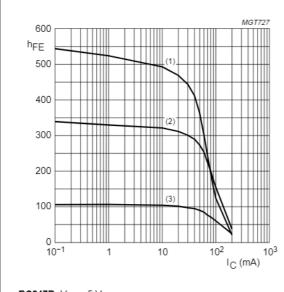
BC846A; I_C/I_B = 10.

- (1) T_{amb} = −55 °C.
- (2) T_{amb} = 25 °C.
- (3) T_{amb} = 150 °C.

Fig.5 Base-emitter saturation voltage as a function of collector current; typical values.

NPN general purpose transistors

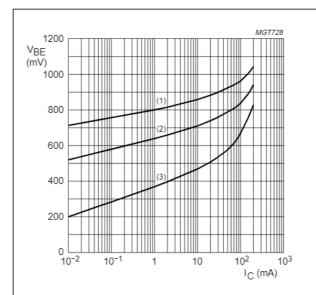
BC846; BC847; BC848



BC847B; V_{CE} = 5 V

- (1) T_{amb} = 150 °C
- (2) T_{amb} = 25 °C.
- (3) T_{amb} = −55 °C

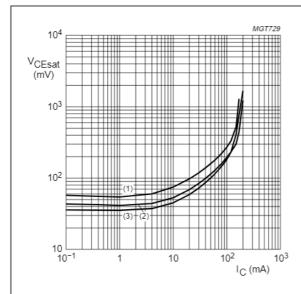
Fig.6 DC current gain as a function of collector current; typical values.



BC847B; V_{CE} = 5 V.

- (1) T_{amb} = -55 °C.
- (2) T_{amb} = 25 °C.
- (3) T_{amb} = 150 °C.

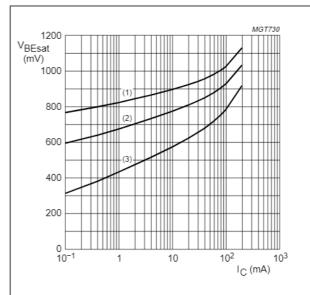
Fig.7 Base-emitter voltage as a function of collector current; typical values.



BC847B; I_C/I_B = 20

- (1) T_{amb} = 150 °C.
- (2) T_{amb} = 25 °C.
- (3) T_{amb} = -55 °C

Fig.8 Collector-emitter saturation voltage as a function of collector current; typical values.



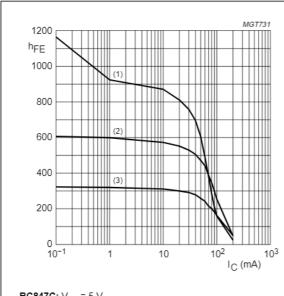
BC847B; I_C/I_B = 10.

- (1) T_{amb} = −55 °C.
- (2) T_{amb} = 25 °C.
- (3) T_{amb} = 150 °C.

Fig.9 Base-emitter saturation voltage as a function of collector current; typical values.

NPN general purpose transistors

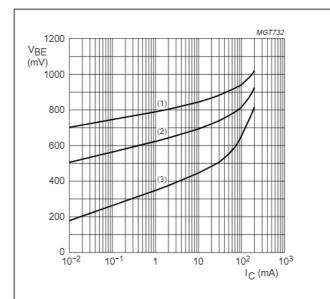
BC846; BC847; BC848



BC847C; V_{CE} = 5 V

- (1) T_{amb} = 150 °C
- (2) T_{amb} = 25 °C
- (3) T_{amb} = −55 °C

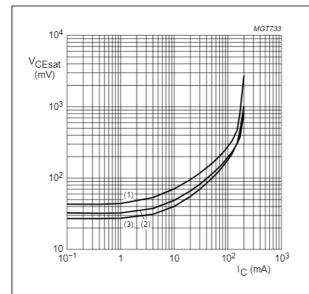
Fig.10 DC current gain as a function of collector current; typical values.



BC847C; V_{CE} = 5 V.

- (1) T_{amb} = -55 °C.
- (2) T_{amb} = 25 °C
- (3) T_{amb} = 150 °C.

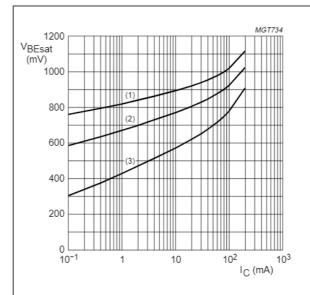
Fig.11 Base-emitter voltage as a function of collector current; typical values.



BC847C; I_C/I_B = 20

- (1) T_{amb} = 150 °C
- (2) T_{amb} = 25 °C.
- (3) T_{amb} = -55 °C.

Fig.12 Collector-emitter saturation voltage as a function of collector current; typical values.



BC847C; I_C/I_B = 10

- (1) T_{amb} = −55 °C.
- (2) T_{amb} = 25 °C.
- (3) T_{amb} = 150 °C.

Fig.13 Base-emitter saturation voltage as a function of collector current; typical values.

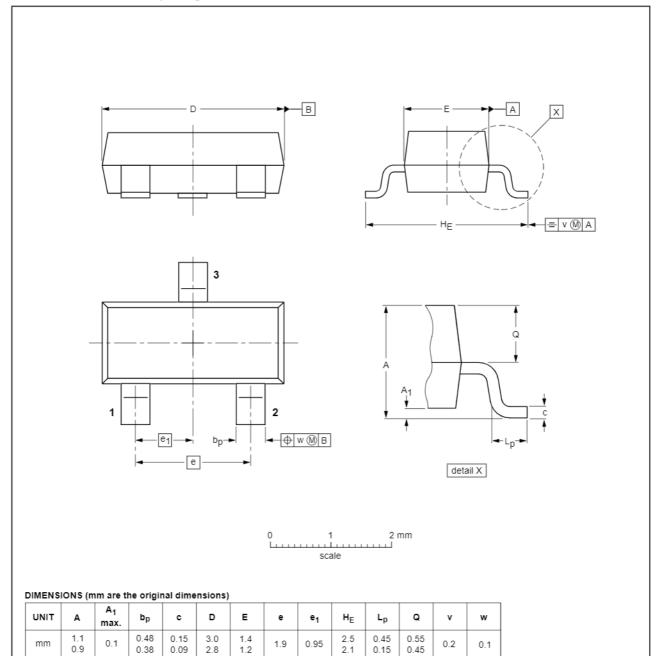
NPN general purpose transistors

BC846; BC847; BC848

PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT23



OUTLINE	REFERENCES			EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ		PROJECTION	1930E DATE
SOT23		TO-236AB				97-02-28 99-09-13

NPN general purpose transistors

BC846; BC847; BC848

DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS(2)(3)	DEFINITION
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